NSN 5961-01-349-0241



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-349-0241 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.000 inches **Overall Diameter:** Between 0.060 inches and 0.107 inches **Function For Which Designed:** Voltage reference **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.55 regulator voltage, dc and 9.45 regulator voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/156 government specification Shelf Life:

N/a **Unit Of Measure:**

Demilitarization:

No

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